



Properties of $\text{Ba}_{0.6}\text{Sr}_{0.4}\text{TiO}_3$ based Coplanar and MIM Varactors

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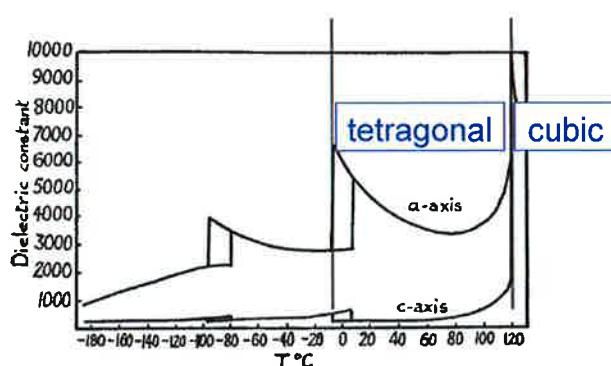


Varactors – motivation / theory



■ Barium-titanium-oxide (BT)

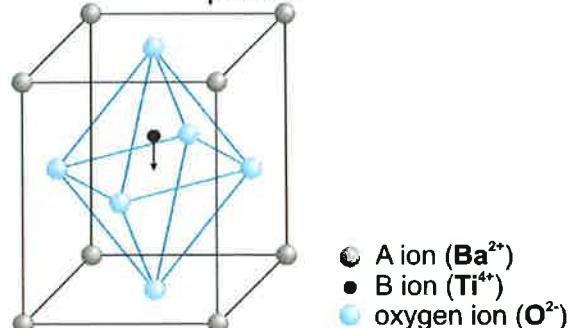
- Perovskite structure
- general formula ABO_3



Devonshire, Philosophical Magazine Series 7, 40, (1949)

unit cell of BaTiO_3

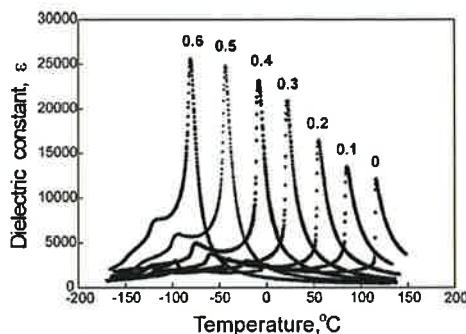
at room temperature



Varactors – motivation / theory

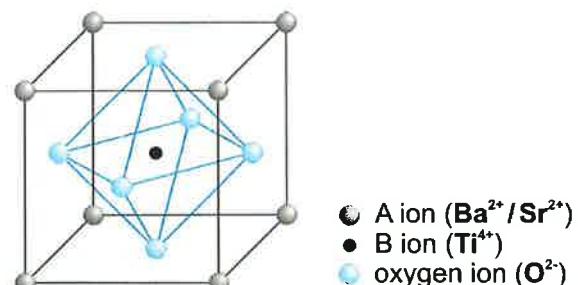
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unit cell of $\text{Ba}_{0.6}\text{Sr}_{0.4}\text{TiO}_3$

at room temperature



BST ($\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$)

- substitution of Ba^{2+} by Sr^{2+}
- SrTiO_3 completely miscible in BaTiO_3
 \rightarrow shift of the phase transition

Jeon, Journal of the European Ceramic Society, 24, 6 (2004)

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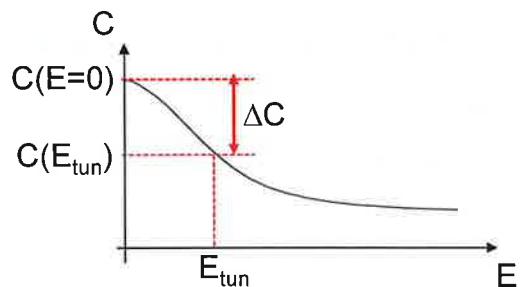
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Varactors – motivation / theory

■ BST as tunable dielectric

- tuning of capacitance/permittivity by an electrical field

$$\tau = \frac{\Delta C}{C(E=0)} = \frac{(C(E=0) - C(E_{tun}))}{C(E=0)}$$



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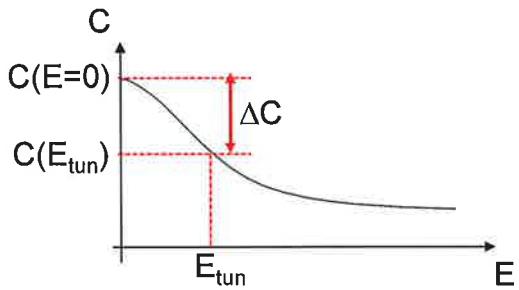
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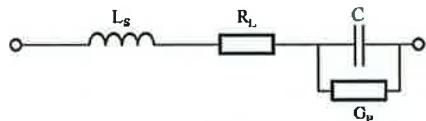
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- loss factor of varactor

$$\frac{1}{Q} = \tan \delta$$



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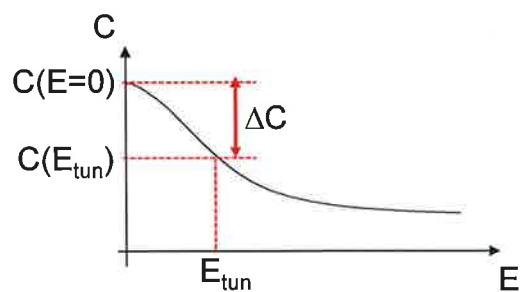
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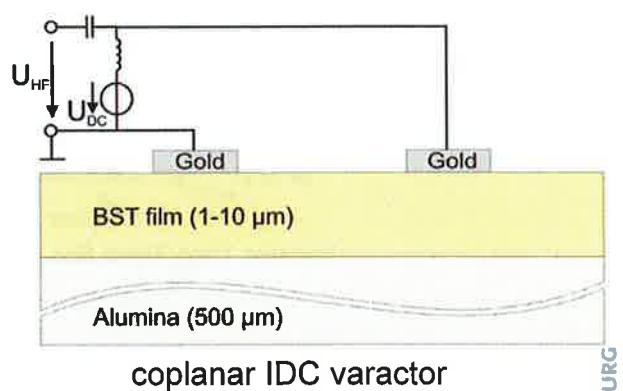
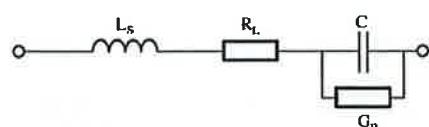
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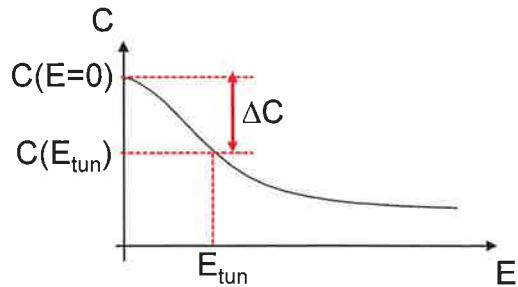
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Varactors – motivation / theory

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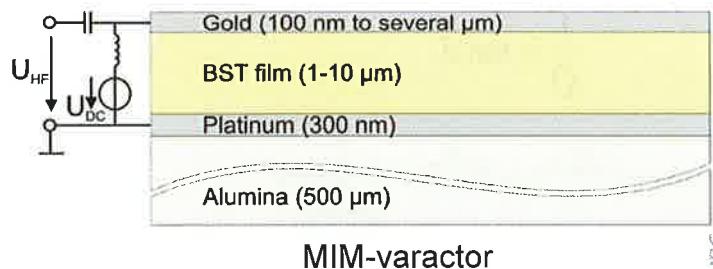
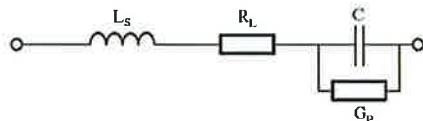
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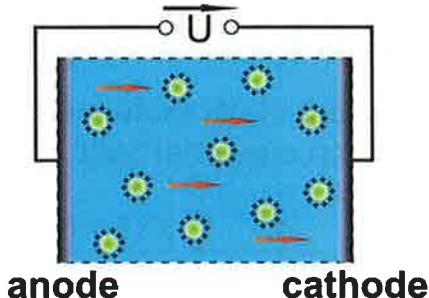
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EPD – motivation / theory

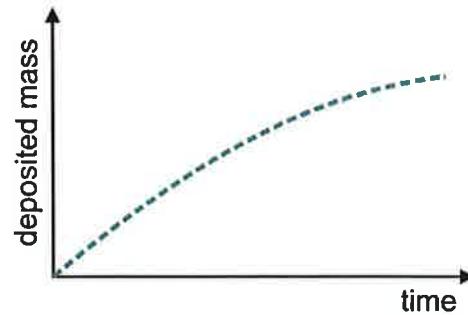
■ Characteristics

- films derived from suspensions
 - deposition enforced by electrical field
 - high homogeneity of green body
 - predictable thickness of films



$$m = c_{solid} \mu \cdot \frac{A_{electr} U \cdot t}{d_{electr}}$$

Hamaker, Trans. Farad. Soc., (1940)



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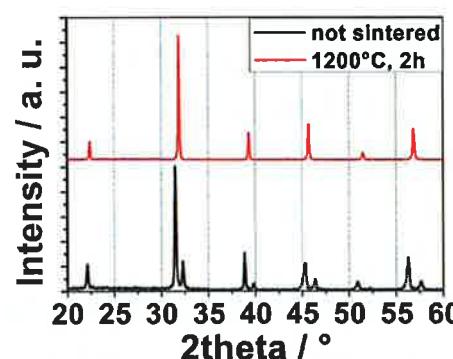
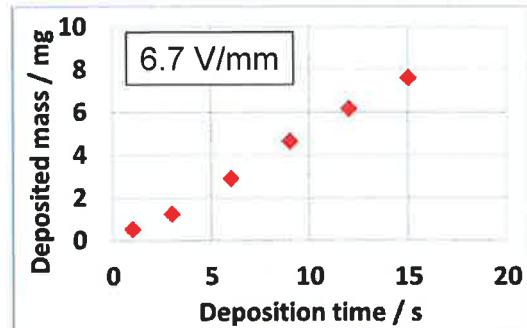
Experimental results - processing of films

■ Film thickness specified by

- electrical field
- deposition time

■ Cofiring

- powder mixture (60 % BaTiO₃, 40 % SrTiO₃)
- 2 h @ 1200°C
- BST formed by interdiffusion of BaTiO₃ and SrTiO₃



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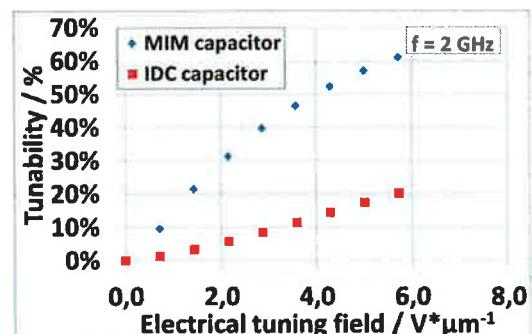
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Experimental results - MIM varactors vs. IDC varactors

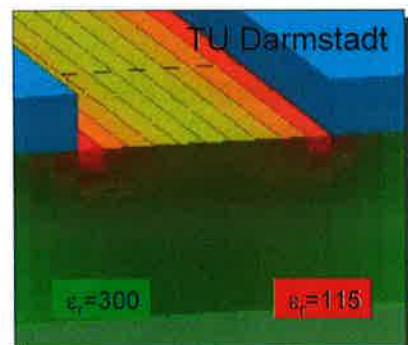
■ Tuning field

- IDCs: Inhomogenous field distribution
- MIMs: Homogenous field distribution



■ Tunability

- up to 60 % at 5 V/μm for MIMs
- good linearity
- MIMs homogeneously tuned
- MIMs superior to IDCs



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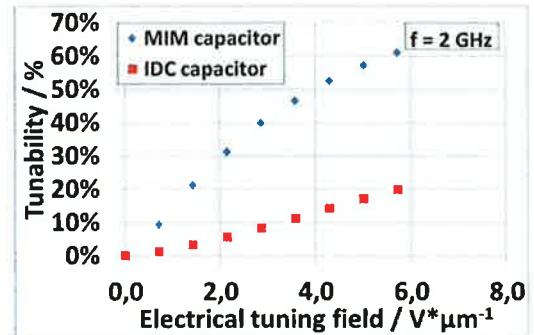
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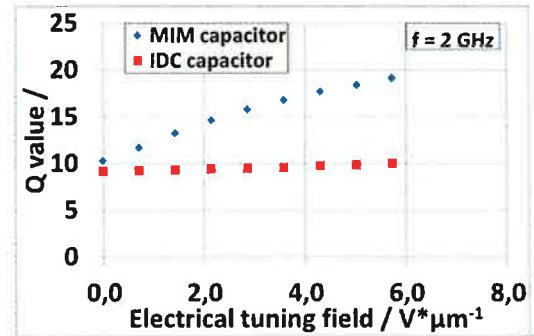
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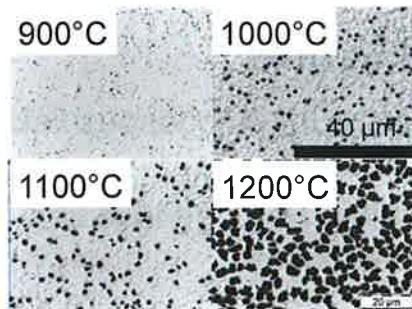
■ Q value

- about 10 without tuning field
- increase with tuning field (MIMs)

Experimental results - MIMs: Electrodes

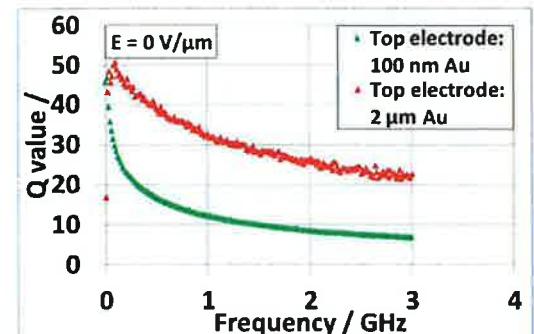
■ Bottom electrode

- 300 nm platinum
- degradation during sintering



■ Top electrode

- galvanically reinforced
- increase of Q from 8 to 26 at 2 GHz
- strong impact of electrode thickness on Q

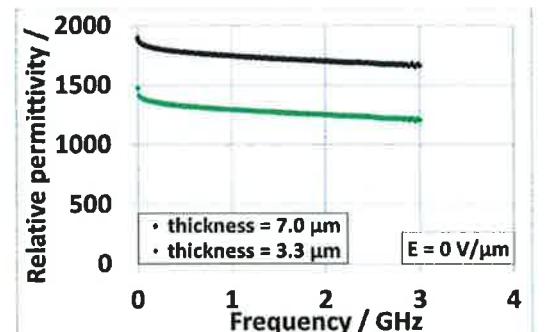
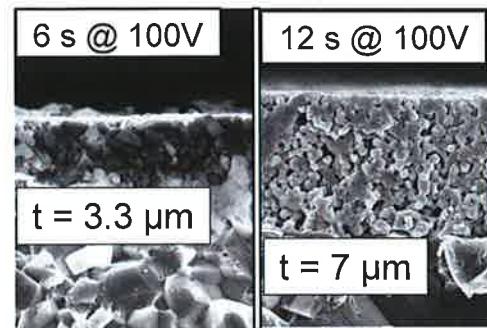


Experimental results - MIMs: Film thickness of BST



■ Permittivity

- decreases slightly with frequency
- decreases with decreased film thickness
- defects in platinum electrode: Reaction between BST and substrate



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Conclusions



- BST is a promising tunable dielectric
- Preparation of BST thick films (1 – 10 μm) via EPD codeposition and cofiring process of BaTiO_3 and SrTiO_3
- MIM structures superior to IDC structures
- Degradation of the bottom electrode (thermal budget)
- Strong influence of electrodes on dielectric properties

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- Karlsruhe Institute of Technology (KIT – IAM)
- Technical University of Darmstadt (TU Darmstadt – IMP)

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Thank you for your attention

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